## UNITED STATES PATENT AND TRADEMARK OFFICE **CERTIFICATE OF CORRECTION**

PATENT NO.

: 6,787,861 B2

Page 1 of 1

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INVENTOR(S) : Lucovsky et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

## Column 12,

Line 4, should read -- 15. The field effect transistor according to claim 3, --Line 9, should read -- 16. The field effect transistor according to claim 3, --Line 13, should read -- 17. The field effect transistor according to claim 3, --

Signed and Sealed this

First Day of February, 2005

JON W. DUDAS Director of the United States Patent and Trademark Office